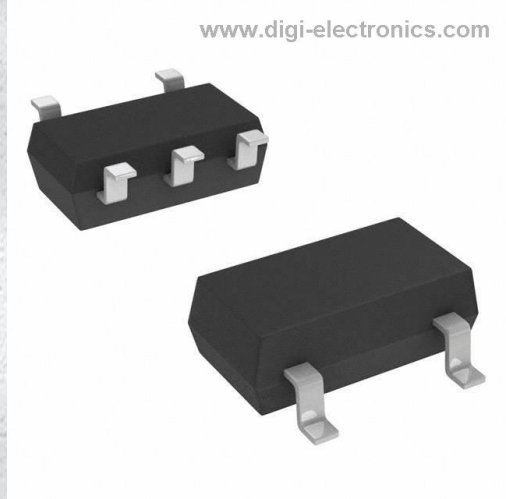
MC74HC1G04DFT1G Datasheet



DiGi Electronics Part Number	MC74HC1G04DFT1G-DG
Manufacturer	onsemi
Manufacturer Product Number	MC74HC1G04DFT1G
Description	IC INVERTER 1CH 1-INP SC88A
Detailed Description	Inverter IC 1 Channel SC-88A (SC-70-5/SOT-353)

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MC74HC1G04DFT1G	onsemi
Series:	Product Status:
74HC	Active
Logic Type:	Number of Circuits:
Inverter	1
Number of Inputs:	Features:
1	-
Voltage - Supply:	Current - Quiescent (Max):
2V ~ 6V	1 µA
Current - Output High, Low:	Input Logic Level - Low:
2.6mA, 2.6mA	0.5V ~ 1.8V
Input Logic Level - High:	Max Propagation Delay @ V, Max CL:
1.5V ~ 4.2V	17ns @ 6V, 50pF
Operating Temperature:	Mounting Type:
-55°C ~ 125°C	Surface Mount
Supplier Device Package:	Package / Case:
SC-88A (SC-70-5/SOT-353)	5-TSSOP, SC-70-5, SOT-353
Base Product Number:	
74HC1G04	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	

onsemi

DATA SHEET
www.onsemi.com

Single Inverter

MC74HC1G04

The MC74HC1G04 is a high speed CMOS inverter fabricated with silicon gate CMOS technology.

The internal circuit is composed of multiple stages, including a buffer output which provides high noise immunity and stable output.

The MC74HC1G04 output drive current is 1/2 compared to MC74HC series.

Features

- High Speed: t_{PD} = 7 ns (Typ) at V_{CC} = 5 V
- Low Power Dissipation: I_{CC} = 1 μA (Max) at T_A = 25°C
- High Noise Immunity
- Balanced Propagation Delays ($t_{pLH} = t_{pHL}$)
- Symmetrical Output Impedance ($I_{OH} = I_{OL}$ = 2 mA)
- Chip Complexity: < 100 FETs
- −Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

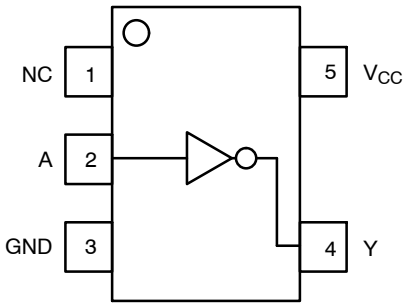


Figure 1. Pinout

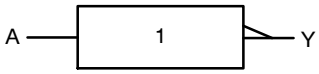
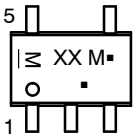


Figure 2. Logic Symbol

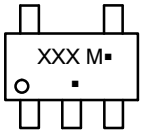
PIN ASSIGNMENT	
1	NC
2	A
3	GND
4	Y
5	V_{CC}

MARKING DIAGRAMS

SC−88A
DF SUFFIX
CASE 419A



SC−74A
DBV SUFFIX
CASE 318BQ



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

FUNCTION TABLE

Input A	Output Y
L	H
H	L

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

MC74HC1G04

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		−0.5 to +6.5	V
V_{IN}	DC Input Voltage		−0.5 to V_{CC} +0.5	V
V_{OUT}	DC Output Voltage		−0.5 to V_{CC} +0.5	V
I_{IK}	DC Input Diode Current		±20	mA
I_{OK}	DC Output Diode Current		±20	mA
I_{OUT}	DC Output Source/Sink Current		±12.5	mA
I_{CC} or I_{GND}	DC Supply Current per Supply Pin or Ground Pin		±25	mA
T_{STG}	Storage Temperature Range		−65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
T_J	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 1)	SC−88A SC−74A	377 320	°C/W
P_D	Power Dissipation in Still Air at 85°C	SC−88A SC−74A	332 390	mW
MSL	Moisture Sensitivity		Level 1	
F_R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V−0 @ 0.125 in	
V_{ESD}	ESD Withstand Voltage (Note 2)	Human Body Model Charged Device Model	2000 1000	V
$I_{LATCHUP}$	Latchup Performance (Note 3)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm−by−1 inch, 20 ounce copper trace with no air flow per JESD51−7.
2. HBM tested to ANSI/ESDA/JEDEC JS−001−2017. CDM tested to JESD22−C101−F. JEDEC recommends that ESD qualification to EIA/JESD22−A115A (Machine Model) be discontinued per JEDEC/JEP172A.
3. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V_{CC}	DC Supply Voltage		2.0	6.0	V
V_{IN}	DC Input Voltage		0.0	V_{CC}	V
V_{OUT}	DC Output Voltage		0.0	V_{CC}	V
T_A	Operating Temperature Range		−55	+125	°C
t_r , t_f	Input Rise and Fall Time	V_{CC} = 2.0 V V_{CC} = 2.3 V to 2.7 V V_{CC} = 3.0 V to 3.6 V V_{CC} = 4.5 V to 6.0 V	0 0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V_{CC} (V)	T_A = 25°C Min	T_A = 25°C Typ	T_A = 25°C Max	−40°C ≤ T_A ≤ 85°C Min	−40°C ≤ T_A ≤ 85°C Max	−55°C ≤ T_A ≤ 125°C Min	−55°C ≤ T_A ≤ 125°C Max	Unit
V_{IH}	High−Level Input Voltage		2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.20	– – – –	– – – –	1.5 2.1 3.15 4.20	– – – –	1.5 2.1 3.15 4.20	– – – –	V
V_{IL}	Low−Level Input Voltage		2.0 3.0 4.5 6.0	– – – –	– – – –	0.5 0.9 1.35 1.80	– – – –	0.5 0.9 1.35 1.80	– – – –	0.5 0.9 1.35 1.80	V
V_{OH}	High−Level Output Voltage	V_{IN} = V_{IH} or V_{IL} I_{OH} = −20 μA	2.0 3.0 4.5 6.0	1.9 2.9 4.4 5.9	2.0 3.0 4.5 6.0	– – – –	1.9 2.9 4.4 5.9	– – – –	1.9 2.9 4.4 5.9	– – – –	V
		V_{IN} = V_{IH} or V_{IL} I_{OH} = −2 mA I_{OH} = −2.6 mA	4.5 6.0	4.18 5.68	4.31 5.80	– –	4.13 5.63	– –	4.08 5.58	– –	
V_{OL}	Low−Level Output Voltage	V_{IN} = V_{IH} or V_{IL} I_{OL} = 20 μA	2.0 3.0 4.5 6.0	– – – –	0.0 0.0 0.0 0.0	0.1 0.1 0.1 0.1	– – – –	0.1 0.1 0.1 0.1	– – – –	0.1 0.1 0.1 0.1	V
		V_{IN} = V_{IH} or V_{IL} I_{OL} = 2 mA I_{OL} = 2.6 mA	4.5 6.0	– –	0.17 0.18	0.26 0.26	– –	0.33 0.33	– –	0.40 0.40	
I_{IN}	Input Leakage Current	V_{IN} = 6.0 V or GND	6.0	–	–	±0.1	–	±1.0	–	±1.0	μA
I_{CC}	Quiescent Supply Current	V_{IN} = V_{CC} or GND	6.0	–	–	1.0	–	10	–	40	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

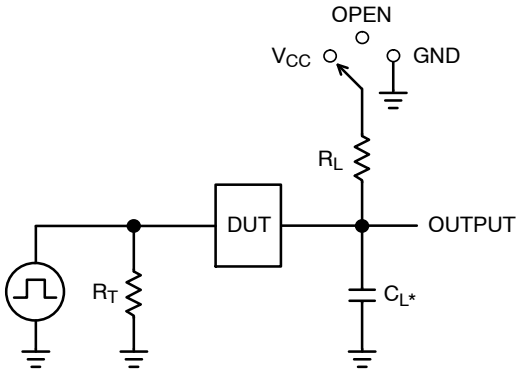
AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	T_A = 25°C Min	T_A = 25°C Typ	T_A = 25°C Max	−40°C ≤ T_A ≤ 85°C Min	−40°C ≤ T_A ≤ 85°C Max	−55°C ≤ T_A ≤ 125°C Min	−55°C ≤ T_A ≤ 125°C Max	Unit
t_{PLH}, t_{PHL}	Propagation Delay, A to Y	V_{CC} = 5.0 V C_L = 15 pF	–	3.5	15	–	20	–	25	ns
		V_{CC} = 2.0 V C_L = 50 pF V_{CC} = 3.0 V V_{CC} = 4.5 V V_{CC} = 6.0 V	– – – –	20 11 8 7	100 27 20 17	– – – –	125 35 25 21	– – – –	155 90 35 26	
t_{TLH}, t_{THL}	Output Transition Time	V_{CC} = 5.0 V C_L = 15 pF	–	3	10	–	15	–	20	ns
		V_{CC} = 2.0 V C_L = 50 pF V_{CC} = 3.0 V V_{CC} = 4.5 V V_{CC} = 6.0 V	– – – –	25 16 11 9	125 35 25 21	– – – –	155 45 31 26	– – – –	200 60 38 32	
C_{IN}	Input Capacitance		–	5	10	–	10	–	10	pF

		Typical @ 25°C, V_{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Note 4)	10	pF

4. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)}$ = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no−load dynamic power consumption; P_D = C_{PD} • V_{CC}^2 • f_{in} + I_{CC} • V_{CC}.

MC74HC1G04

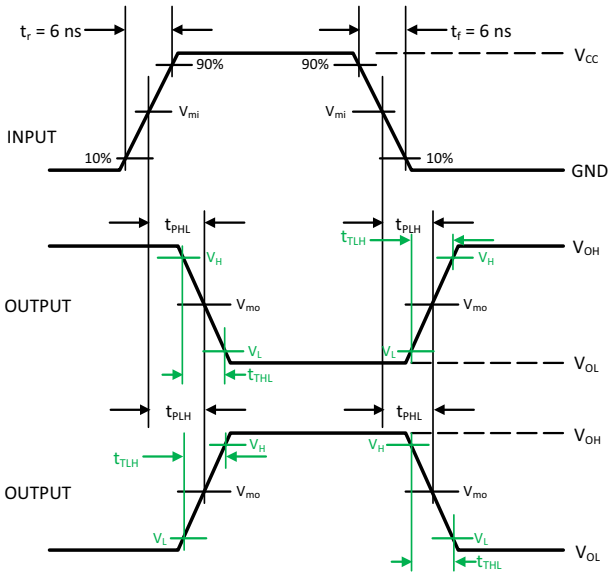


Test	Switch Position	C_L, pF	R_L, Ω
t_{PLH} / t_{PHL}	Open	See AC Characteristics Table	X
t_{TLH} / t_{THL} (Note 5)	Open		X
t_{PLZ} / t_{PZL}	V_{CC}		1 k
t_{PHZ} / t_{PZH}	GND		1 k

X – Don't Care

*C_L includes probe and jig capacitance
R_T is Z_{OUT} of pulse generator (typically 50 W)
f = 1 MHz

Figure 3. Test Circuit



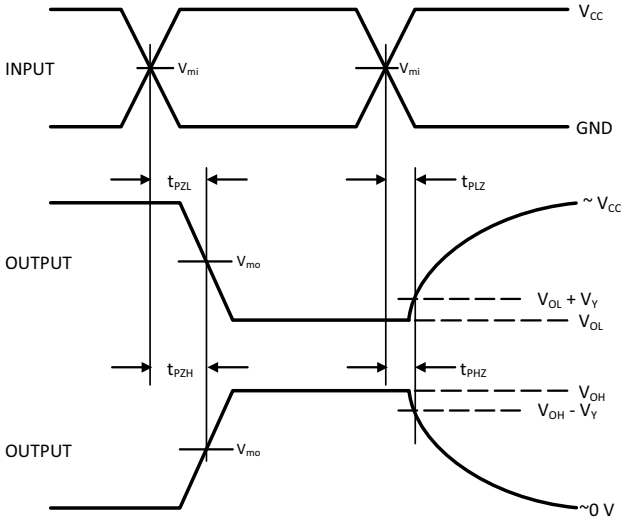


Figure 4. Switching Waveforms

V_{CC}, V	V_{mi}, V	V_{mo}, V		V_L, V	V_H, V	V_Y, V
		t_{PLH}, t_{PHL}	t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}			
3.0 to 3.6	V_{CC}/2	V_{CC}/2	V_{CC}/2	V_{OL} + 0.1 (V_{OH} – V_{OL})	V_{OL} + 0.9 (V_{OH} – V_{OL})	0.3
4.5 to 5.5	V_{CC}/2	V_{CC}/2	V_{CC}/2	V_{OL} + 0.1 (V_{OH} – V_{OL})	V_{OL} + 0.9 (V_{OH} – V_{OL})	0.3

5. t_{TLH} and t_{THL} are measured from 10% to 90% of (V_{OH} – V_{OL}), and 90% to 10% of (V_{OH} – V_{OL}), respectively.

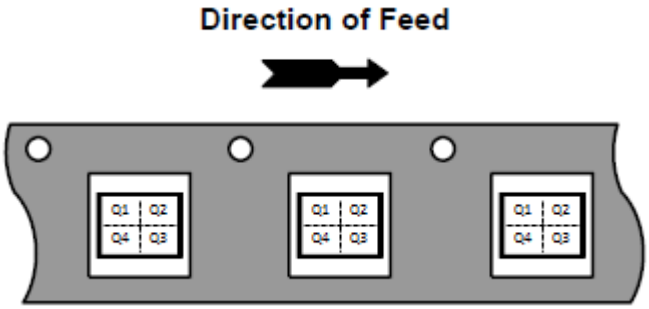
ORDERING INFORMATION

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping†
MC74HC1G04DFT1G	SC−88A	H5	Q2	3000 / Tape & Reel
MC74HC1G04DFT1G−Q* (Please contact **onsemi**)	SC−88A	H5	Q2	3000 / Tape & Reel
MC74HC1G04DFT2G	SC−88A	H5	Q4	3000 / Tape & Reel
MC74HC1G04DFT2G−Q* (Please contact **onsemi**)	SC−88A	H5	Q4	3000 / Tape & Reel
MC74HC1G04DBVT1G	SC−74A	H5	Q4	3000 / Tape & Reel

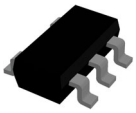
†For complete information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*−Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

Pin 1 Orientation in Tape and Reel

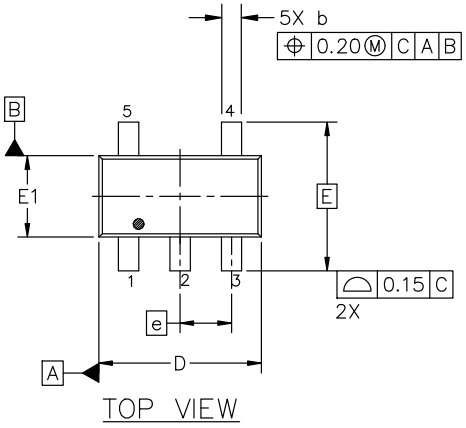


MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

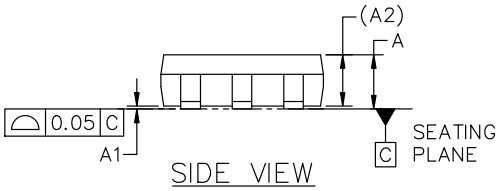


SC−74A−5 3.00x1.50x0.95, 0.95P
CASE 318BQ
ISSUE C

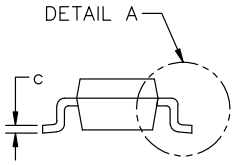
DATE 26 FEB 2024



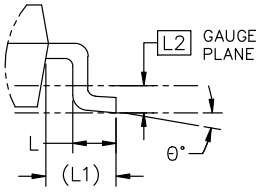
TOP VIEW



SIDE VIEW



END VIEW



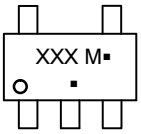
DETAIL "A"
SCALE 2:1

NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5−2018.
2. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.90	1.00	1.10
A1	0.01	0.18	0.10
A2		0.95 REF.	
b	0.25	0.37	0.50
c	0.10	0.18	0.26
D	2.85	3.00	3.15
E		2.75 BSC	
E1	1.35	1.50	1.65
e		0.95 BSC	
L	0.20	0.40	0.60
L1		0.62 REF.	
L2		0.25 BSC	
θ	0°	5°	10°

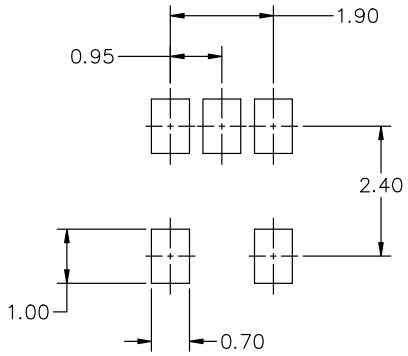
GENERIC MARKING DIAGRAM*



XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot " ▪", may or may not be present. Some products may not follow the Generic Marking.



RECOMMENDED MOUNTING FOOTPRINT*

* FOR ADDITIONAL INFORMATION ON OUR Pb−FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

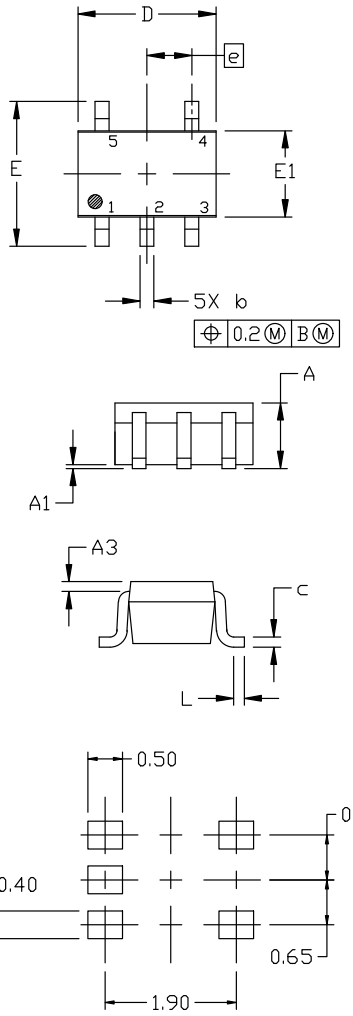
DOCUMENT NUMBER:	**98AON66279G**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	**SC−74A−5 3.00x1.50x0.95, 0.95P**		**PAGE 1 OF 1**

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

SCALE 2:1

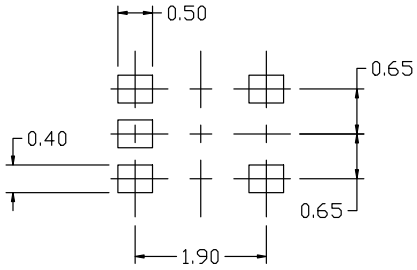
SC−88A (SC−70−5/SOT−353)
CASE 419A−02
ISSUE M

DATE 11 APR 2023



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS
3. 419A−01 OBSOLETE. NEW STANDARD 419A−02
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

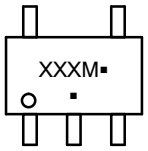
DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.95	1.10
A1	---	---	0.10
A3	0.20 REF		
b	0.10	0.20	0.30
c	0.10	---	0.25
D	1.80	2.00	2.20
E	2.00	2.10	2.20
E1	1.15	1.25	1.35
e	0.65 BSC		
L	0.10	0.15	0.30



RECOMMENDED
MOUNTING FOOTPRINT

* For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

STYLE 1:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 2:
PIN 1. ANODE
2. EMITTER
3. BASE
4. COLLECTOR
5. CATHODE

STYLE 3:
PIN 1. ANODE 1
2. N/C
3. ANODE 2
4. CATHODE 2
5. CATHODE 1

STYLE 4:
PIN 1. SOURCE 1
2. DRAIN 1/2
3. SOURCE 1
4. GATE 1
5. GATE 2

STYLE 5:
PIN 1. CATHODE
2. COMMON ANODE
3. CATHODE 2
4. CATHODE 3
5. CATHODE 4

STYLE 6:
PIN 1. EMITTER 2
2. BASE 2
3. EMITTER 1
4. COLLECTOR
5. COLLECTOR 2/BASE 1

STYLE 7:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 8:
PIN 1. CATHODE
2. COLLECTOR
3. N/C
4. BASE
5. EMITTER

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. ANODE
5. ANODE

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

DOCUMENT NUMBER:	**98ASB42984B**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.	
DESCRIPTION:	**SC−88A (SC−70−5/SOT−353)**		**PAGE 1 OF 1**

ADDITIONAL INFORMATION

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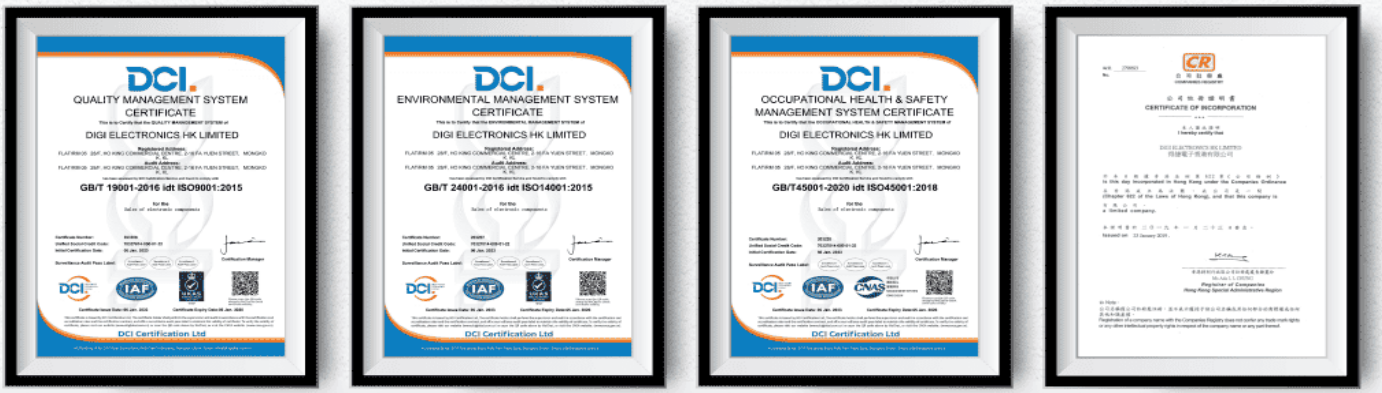

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